

Calibrated 12-Bit ADC with T/H and Reference

ABSOLUTE MAXIMUM RATINGS

V _{DD} to DGND	-0.3V, +17V	Operating Temperature Range	
V _{SS} to DGND	+0.3V, -7V	MAX178_C	0 C to +70 C
AGND to DGND	-0.3V, REFIN +0.3V	MAX178_E	-40 C to +85 C
V _{CC} to DGND	-0.3V, +7V	MAX178_M	-55 C to +125 C
REFIN to AGND	-0.3V, V _{DD} +0.3V	Power Dissipation (any Package)	
AIN to AGND	-0.3V, V _{DD} +0.3V	To +75 C	1,000mW
Digital Input Voltage to DGND	-0.3V, V _{DD} +0.3V	Derate above +75 C by	10mW/C
Digital Output Voltage to DGND	-0.3V, V _{DD} +0.3V	Storage Temperature	-65 C to +150 C
		Lead Temperature (Soldering, 10 sec.)	+300 C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at those or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

(V_{DD} = +15V, V_{CC} = +5V, V_{SS} = -5V, REFIN = +5.0V, all specifications T_A = T_{MIN} to T_{MAX}, f_{CLK} = 266.67kHz external, unless otherwise

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
ACCURACY						
Resolution			12			Bits
Total Unadjusted Error (Note 1)	TUE				±1	LSB
Differential Nonlinearity	DNL	No missing codes guaranteed			±1	LSB
Full-Scale Error (Gain Error)		T _A = +25 C			±1/2	LSB
Full-Scale Error Tempco				0.5		ppm/ C
Zero Error		T _A = +25 C			±1/2	LSB
Zero Error Tempco				0.5		ppm/ C
ANALOG INPUT						
Input Voltage Range		V _{REF} = +5V	0		+5	V
On-Channel Input Capacitance	C _{AIN}			8		pF
Input Leakage Current	I _{AIN}	A _{IN} = 0V to +5V; T _A = +25 C T _A = T _{MIN} to T _{MAX}			10 100	nA
DYNAMIC ACCURACY (f _{WR} = 14.81kHz, f _{AIN} = 2.011kHz, T _A = 25 C, Note 2)						
Signal-to-Noise + Distortion	S/(N + D)		70			dB
Total Harmonic Distortion	THD				-80	dB
Peak Harmonic or Spurious Noise					-80	dB
REFERENCE INPUT						
REFIN Range	V _{REFIN}	For specified performance Degraded transfer accuracy	+4	+5 ±5%	+6	V
REFIN Input Current		REFIN = +5V			1.0	mA
REFERENCE OUTPUT						
MAX178A						
REFOUT Voltage		T _A = +25 C	+4.985	+5	+5.015	V
REFOUT Temp (C°)				±10	±40	ppm/ C
REFOUT Sink Current					1	mA
MAX178B						
Use External Reference Only						

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ELECTRICAL CHARACTERISTIC (continued)

(V_{DD} = +15V, V_{CC} = +5V, V_{SS} = -5V, REFIN = +5.0V, all specifications T_A = T_{MIN} to T_{MAX}, f_{CLK} = 266.67kHz external, unless otherwise noted)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
LOGIC INPUTS						
RD, CS, WR, BYSL						
Input High Voltage	V _{IH}	V _{CC} = +5V ±5%	+2.4			V
Input Low Voltage	V _{IL}	V _{CC} = +5V ±5%			+0.8	V
Input Current	I _{IN}	V _{IN} = 0 to V _{CC} : T _A = +25°C T _A = T _{MIN} to T _{MAX}			±1 ±10	μA
Input Capacitance	C _{IN}	(Note 3)			10	pF
CLOCK						
Input High Voltage	V _{IH}	V _{CC} = +5V ±5%	+3.0			V
Input Low Voltage	V _{IL}	V _{CC} = +5V ±5%			+0.8	V
Input High Current	I _{IH}	V _{CC} = +5V ±5%			1.5	mA
Input Low Current	I _{IL}	V _{CC} = +5V ±5%			1.2	mA
LOGIC OUTPUTS						
DB0-DB7, BUSY						
Output High Voltage	V _{OH}	V _{CC} = +5V ±5%, I _{SOURCE} = 200μA	+4.0			V
Output Low Voltage	V _{OL}	V _{CC} = +5V ±5%, I _{SINK} = 1.6mA			+0.4	V
Floating State Leakage Current (DB0-DB7)	I _{LKG}	V _{OUT} = 0V to V _{CC}			±1	μA
Floating State Output Capacitance (DB0-DB7)	C _{OUT}	(Note 3)			15	pF
CONVERSION TIME (Note 4)						
With External Clock		f _{CLK} = 266.67kHz	60			μs
With Internal Clock		T _A = +25°C	90		140	μs
POWER REQUIREMENTS (Note 5)						
Power-Supply Voltage	V _{DD}		+11.4		+15.75	V
	V _{SS}		-4.75		-5.25	
	V _{CC}		+4.75		+5.25	
V _{DD} Supply Rejection		V _{DD} = +14.25V to +15.75V, V _{SS} = -5V		±1/8		LSB
V _{SS} Supply Rejection		V _{SS} = -4.75V to -5.25V, V _{DD} = +15V		±1/8		LSB
V _{DD} Supply Rejection		V _{DD} = +11.4V to +12.6V, V _{SS} = -5V		±1/8		LSB
V _{SS} Supply Rejection		V _{SS} = -4.75V to -5.25V, V _{DD} = +12V		±1/8		LSB
Power-Supply Current	I _{DD}	V _{IN} = V _{IL} or V _{IH}		6	10	mA
	I _{SS}				8	
	I _{CC}			0.1	1.0	

Note 1: Includes: Full-Scale Error, Offset Error, Relative Accuracy.

Note 2: Up to 5th Harmonic is measured.

Note 3: Guaranteed by design.

Note 4: Track/Hold acquisition time included in conversion time, using t₁₃ condition (see Timing Characteristics).

Note 5: Power-supply current is measured when MAX178 is inactive (CS = WR = RD = BUSY = High).

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TIMING CHARACTERISTICS (Note 6, Figures 1 and 2)

(V_{DD} = +15V, V_{CC} = +5V, V_{SS} = -5V, REFIN = +5.0V, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	T _A = +25°C			T _A = -40°C to +85°C			T _A = -55°C to +125°C			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
CS to \overline{WR} Setup Time	t ₁		0			0			0			ns
\overline{WR} Pulse Width	t ₂		120			120			120			ns
CS to \overline{WR} Hold Time	t ₃		0			0			0			ns
\overline{WR} to BUSY Propagation Delay	t ₄			85	120		100	140		115	160	ns
BUSY to CS Setup Time	t ₅	(Note 3)	0			0			0			ns
CS to \overline{RD} Setup Time	t ₆		0			0			0			ns
\overline{RD} Pulse Width	t ₇		120			120			120			ns
CS to \overline{RD} Hold Time	t ₈		0			0			0			ns
BYSL to \overline{RD} Setup Time	t ₉		50			50			50			ns
BYSL to \overline{RD} Hold Time	t ₁₀		0			0			0			ns
\overline{RD} to Valid Data (Note 7)	t ₁₁	(Bus Access Time)		60	100		70	110		90	130	ns
\overline{RD} to Three-State Output (Note 8)	t ₁₂	(Bus Relinquish Time)	20		100	20		100	20		100	ns
\overline{WR} to CLK for 16 Clock Conversions (Note 9)	t ₁₃		20			20			20			ns
\overline{WR} to CLK for 17 Clock Conversions (Note 9)	t ₁₄		20			20			20			ns

Note 6: Data is timed from V_{OH}, V_{OL}; all input control signals are timed from a voltage level of +1.6V and specified with t_r = t_f = 20ns (10% to 90% of +5V).

Note 7: t₁₁, the time required for an output to cross 0.8V or 2.4V, is measured with the load circuits of Figure 3.

Note 8: t₁₂, the time required for the data lines to change 0.5V, is measured with the load circuits of Figure 4.

Note 9: See Figure 7.

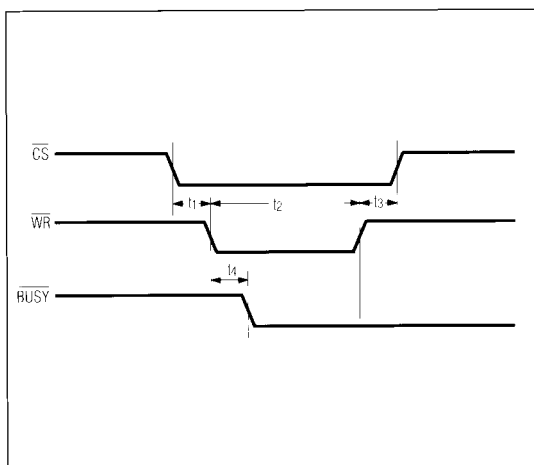


Figure 1: Start Cycle Timing

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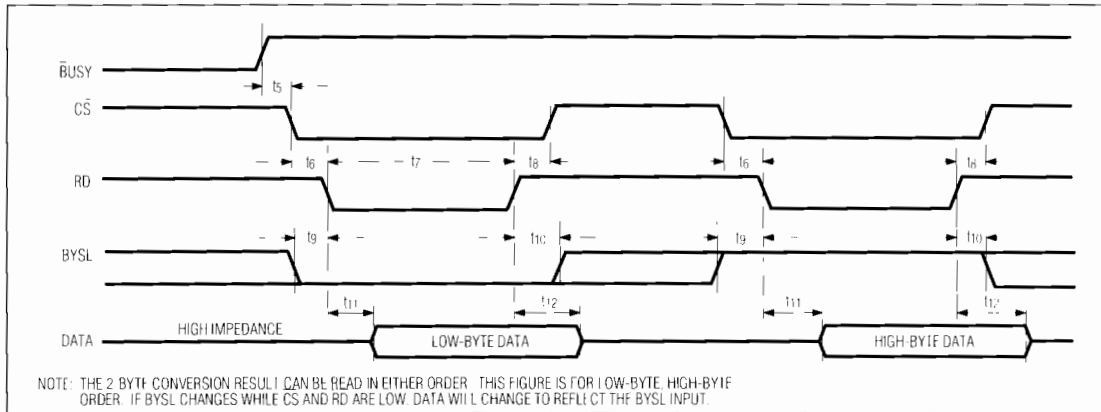


Figure 2. Read Cycle Timing

Pin Description

PIN	NAME	FUNCTION
1	CAZ	Auto-Zero Capacitor Input. Connect other end of capacitor to AGND.
2	AIN	Analog Input
3	N.C.	No Connect
4	REFIN	Voltage Reference Input. The MAX178 is specified with REFIN = +5V.
5	AGND	Analog Ground
6	DGND	Digital Ground
7	VCC	Logic Supply. Digital inputs and outputs are TTL compatible for VCC = +5V.
8-15	DB0-DB7	Three-State Data Outputs. Active when CS and RD are brought low. Individual pin functions depend upon BYTE SELECT (BYSL) input.

DATA BUS OUTPUT, CS, RD = LOW

PIN	BYSL = HIGH	BYSL = LOW
8	BUSY (Note 10)	DB7
9	LOW (Note 11)	DB6
10	LOW (Note 11)	DB5
11	LOW (Note 11)	DB4
12	DB11 (MSB)	DB3
13	DB10	DB2
14	DB9	DB1
15	DB8	DB0 (LSB)

PIN	NAME	FUNCTION
16	RD	READ Input. Used with CS to enable the three-state data outputs. RD is active low.
17	CS	CHIP SELECT Input. Used with either RD or WR for control. CS is active low.
18	WR	WRITE Input. In combination with CS, this active low signal starts a new conversion.
19	BYSL	BYTE SELECT. BYSL selects high- or low-byte output during a data READ operation. (RD, CS = low). See pins 8-15.
20	BUSY	Converter Status. BUSY is only low during conversion.
21	CLK	CLOCK Input. Internal clock operation, with this pin floating and unloaded, typically results in 120µs conversion time (Figure 8). This can be lowered by using an external 74HC clock source (Figure 9).
22	REFOUT	Reference Output
23	VSS	Negative Supply Voltage, -5V
24	VDD	Positive Supply Voltage, +15V

Note 10: High during a conversion. BUSY is a converter status flag.

Note 11: When BYSL is high, pins 9-11 output a logic low. The 12-bit digital result is in DB0-DB11. DB11 is the MSB.

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Detailed Operation Operating Information

Figure 5 shows an operational diagram for the MAX178. The only required passive components are a hold capacitor (CAZ) and a reference bypass capacitor and resistor. Individual pin functions are listed in the Pin Description table.

On-Chip Clock Operation

The on-chip oscillator requires no external components. Therefore, the CLK pin can be left unconnected resulting in a typical 120µs conversion time. The conversion time can be increased by adding a capacitive load on the CLK pin. The timing diagrams in Figures 6 and 7 show the resulting tracking duration for relative positions of WR and CLK. Figure 8 is a schematic for on-chip clock operation.

A new conversion is initiated by bringing \overline{WR} low, with CS low. This starts a track acquisition sequence. In this state, the T/H goes into track mode. Capacitor CAZ charges to the analog input voltage minus the input offset voltage of the comparator. Note: when \overline{WR} is low (with CS low), the MAX178 is in track mode. When \overline{WR} goes high, tracking time is extended by another 4 to 5 clock periods (4 clock periods beginning with the first falling clock edge following the rising edge of \overline{WR}). 16 to 17 clock periods are required for each conversion (Figure 7).

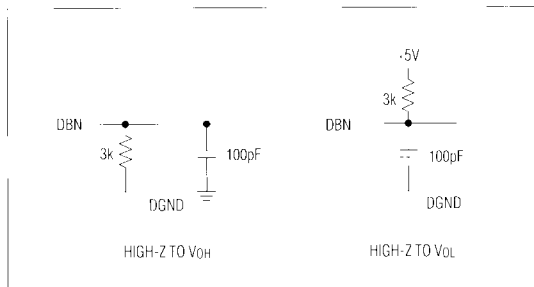


Figure 3. Load Circuits for Access Time Test (t_{11})

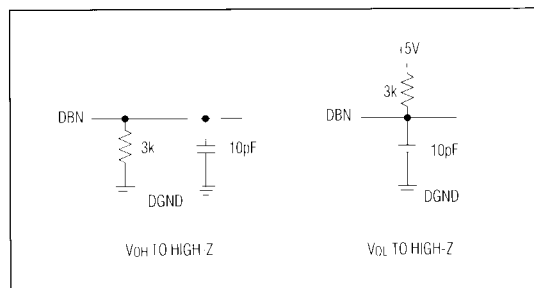


Figure 4. Load Circuits for Output Three-State Delay Test (t_{12})

The MAX178 is in track mode between conversions when \overline{BUSY} is high. After the tracking sequence, the most significant bit (MSB) decision is made. Following this, the remaining 11 bits are digitized on successive clock cycles, as indicated in Figure 6. The \overline{WR} pulse need not be synchronized with the internal clock.

External Clock Operation

For external clock operation, drive the CLK input with a 74HC compatible clock source (Figure 9).

The MAX178 automatically tracks for the appropriate time by means of an on-chip counter. Both \overline{WR} and CS must be low to initiate a new conversion. Whenever \overline{WR} and CS are low, the chip enters into track mode until \overline{WR} or CS rises. After the rising edge of \overline{WR} , the next falling edge of the clock starts a counter, which extends the tracking time by 4 to 5 external clock periods.

The analog input acquisition is complete at the end of the tracking period, and the signal is stored in the internal track-and-hold. The external clock source need not be synchronized with the \overline{WR} pulse.

Reading Data

The 12-bit result of a conversion plus the converter status flag are accessible over an 8-bit data bus. The data is available from the MAX178 in right-justified format (the least significant bit (LSB) is the right-most bit in a 16-bit word). Two byte sized read operations are needed. The Byte Select (BYSL) input determines which byte is to be read first, 8LSBs or 4MSBs plus status flag.

It is necessary to wait for the end of a conversion to obtain valid 12-bit data from the MAX178's successive approx-

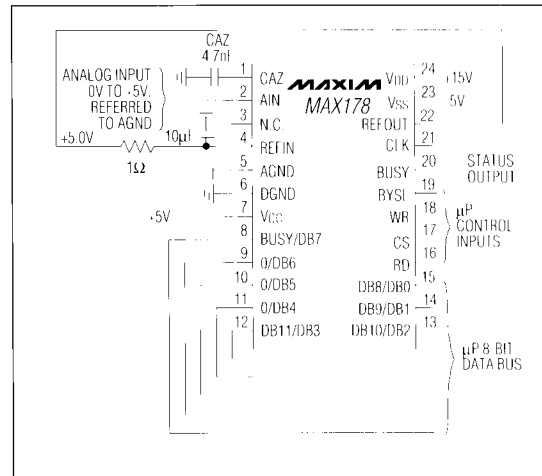


Figure 5. MAX178 Operational Diagram

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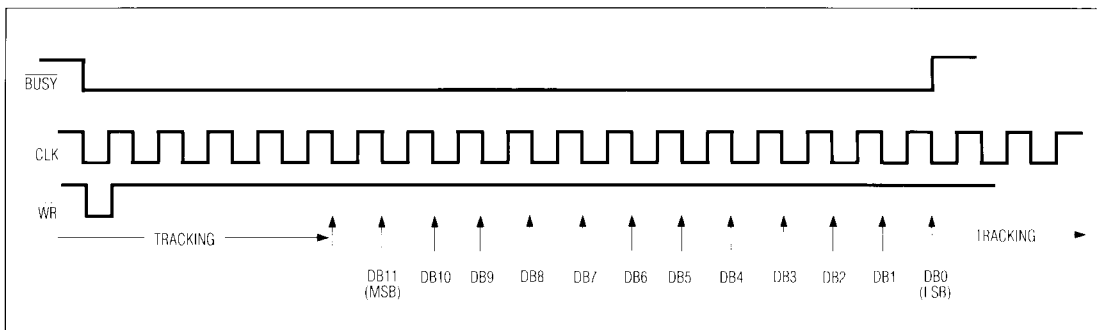


Figure 6. MAX178 Timing Diagram

imation register (SAR). If a read operation instruction is performed during a conversion, the MAX178 will dump the existing contents of the SAR onto the data bus. There are three methods to ensure correct operation:

1. Insert a software delay longer than the ADC conversion time between the conversion start and the data read operations.
2. The $\overline{\text{BUSY}}$ output is low during the conversion and high at the conversion end. Use this signal as an interrupt to the μP .
3. Poll the converter status flag, BUSY , at user-defined intervals after a conversion start. The status flag is available on DB7 during a high-byte READ. The flag is the left-most bit and can be shifted directly into the μP 's carry flag for testing. BUSY is high during a conversion.

A write operation to the MAX178 during a conversion restarts the conversion.

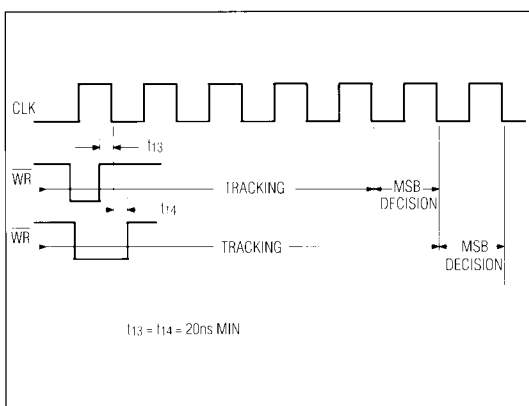


Figure 7. Width of Tracking Interval as a Function of WR Rising Edge Timing with Respect to CLK Falling Edge

Application Hints

Auto-Zero Capacitor (CAZ)

CAZ (Figure 5) must be a low-leakage, low-dielectric absorption capacitor such as polypropylene, polystyrene, or teflon. Connect the outside foil of CAZ to AGND to minimize noise. CAZ should be 4,700pF.

Clock

Figure 10 shows typical conversion time versus temperature when using the MAX178's on-chip clock. Due to variations in manufacturing, the actual operating frequency can differ from chip-to-chip by up to 20%. For this reason, it is suggested that an external clock be used when fixed conversion times are required.

Analog Inputs

The high-impedance analog input, AIN, allows simple analog interfacing. Signal sources from 0V to +5V may be connected directly to AIN without extra buffering for source impedances up to 5k Ω (Figure 11). The input/output (I/O) transfer characteristic and transition points for this input signal range are demonstrated in Figure 12 and Table 1. The MAX178 transfer characteristic has transi-

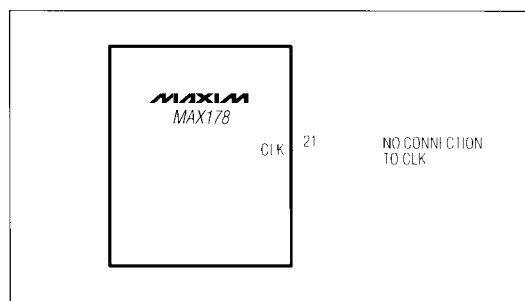


Figure 8. Internal Clock Operation

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tion points designed to occur on integer multiples of 1LSB. The output code is natural binary with:

$$1\text{LSB} = (\text{Full Scale (FS)})/4096 \\ = (5/4096)\text{V} = 1.22\text{mV}$$

For signal ranges other than 0V to +5V, use resistor divider networks to provide 0V to +5V signal ranges at the MAX178 input pins. The connection in Figure 13 shows a divider network for a 0V to +10V signal range. Resistors should be of the same type and manufacturer to ensure matched temperature coefficients. The source impedance must now be as low as possible since it adds to the resistor divider impedance.

Figure 14 shows how bipolar signals -5V to +5V are accommodated by referencing the resistor divider network to REFIN. The signal source must be capable of

sinking 0.5mA with the resistor values shown. Refer to Figure 15 and Table 2 for the I/O transfer characteristic and transition points for this signal range. Output coding is offset binary with an LSB size of:

$$(\text{FS})(1/4096) = (10/4096)\text{V} = 2.44\text{mV}$$

To adjust bipolar zero error, apply 1.22mV (+1/2LSB) to AIN and adjust the offset of A1 so that the ADC output switches between 1000 0000 0000 and 1000 0000 0001.

Power-Supply Decoupling

Power supplies to the MAX178 should be bypassed with either a 10µF electrolytic or tantalum capacitor in parallel with a 0.01µF disc ceramic capacitor for clean, high-frequency performance. Place all capacitors as close as possible to the MAX178 supply pins.

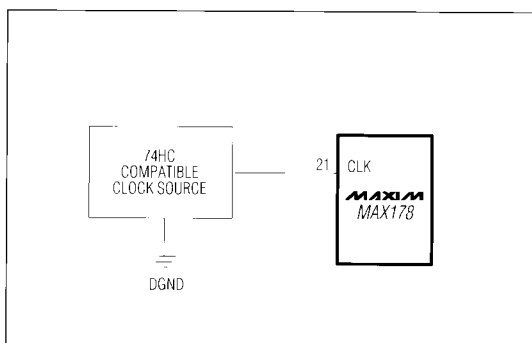


Figure 9. External Clock Operation

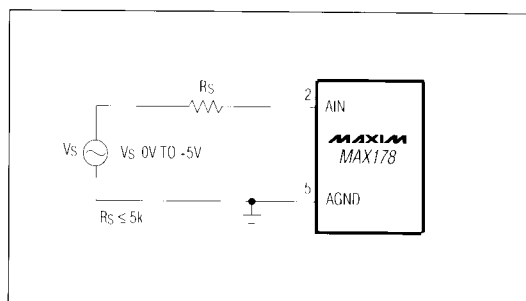


Figure 11. Unipolar 0V to +5V Operation

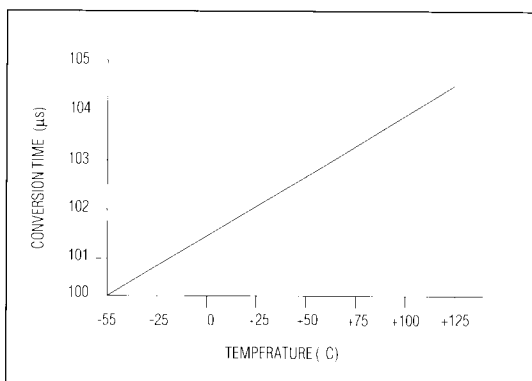


Figure 10. Typical Change in Conversion Time Variation vs. Temperature when Using Internal Clock

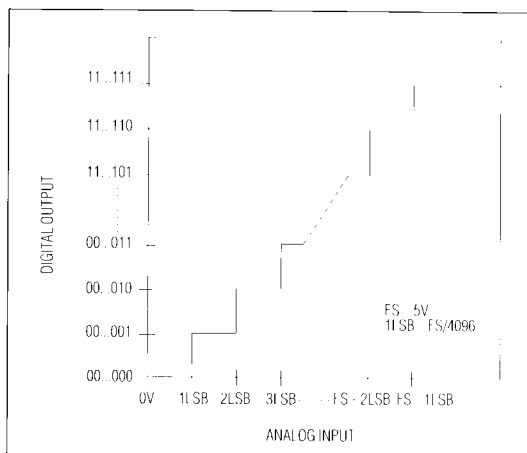


Figure 12. Ideal Input/Output Transfer Characteristic for Unipolar Circuit of Figure 11

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Internal Reference

The internal reference (REFOUT) should be bypassed with a 1Ω resistor in series with a capacitor. The capacitor should be a $10\mu\text{F}$ electrolytic or tantalum in parallel with a $0.01\mu\text{F}$ disc ceramic (Figure 16). Figure 17 shows a circuit that allows input adjustment which is useful for trimming out initial (room temperature) error in the reference voltage.

External Reference Circuit

Figure 18 shows how to set up a MX584LH to generate a reference voltage of 5.00V . A typical adjustment range of 75mV is provided by R2. Over the commercial temperature range, the MX584LH contributes no more than $\pm 1\text{LSB}$ of gain error.

During a conversion, transient currents flow at the REFIN input. To prevent dynamic errors, place either a $10\mu\text{F}$ electrolytic or tantalum smoothing capacitor in parallel with a $0.01\mu\text{F}$ disc ceramic from the REFIN pin to AGND.

Table 1. Transition Points for Unipolar 0V to +5V Operation

Analog Input (V)	Digital Output
0.00122	0000 0000 0001
0.00244	0000 0000 0010
...	...
2.49878	0111 1111 1111
2.50000	1000 0000 0000
2.50122	1000 0000 0001
...	...
4.99756	1111 1111 1110
4.99878	1111 1111 1111

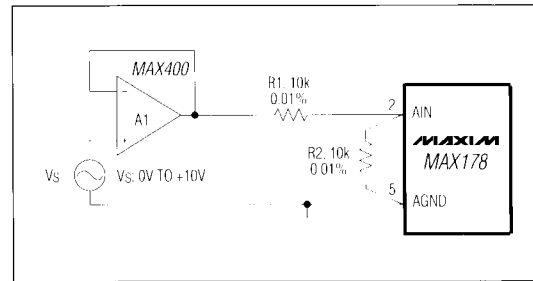


Figure 13. Unipolar 0V to +10V Operation

Table 2. Transition Points for Bipolar -5V to +5V Operation

Analog Input (V)	Digital Output
-4.99878	0000 0000 0001
-4.99634	0000 0000 0010
...	...
-0.00122	1000 0000 0000
+0.00122	1000 0000 0001
...	...
+4.99389	1111 1111 1110
+4.99634	1111 1111 1111

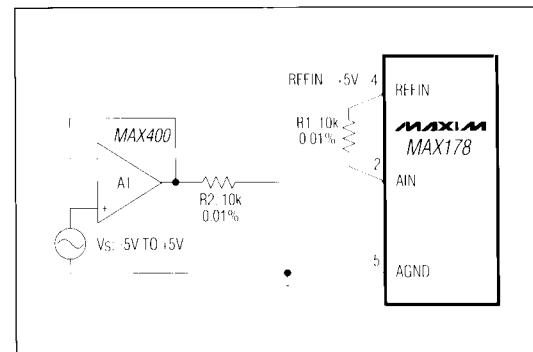


Figure 14. Bipolar -5V to +5V Operation

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Layout

When designing layout for a printed circuit board, keep digital and analog signal lines separated whenever possible. It is critical that no digital line runs alongside an analog signal line or near the CAZ. Guard the analog inputs, the reference input and the CAZ input with AGND.

Establish a single-point analog ground (AGND) as close to the MAX178 as possible, isolated from the logic system. Connect the single-point analog ground to the digital system ground, which is attached to DGND at one point, as close as possible to the MAX178. The following should be returned to the analog ground point: input-signal common, input guards, the CAZ, and any bypass capacitors for the reference input and the analog supplies. Low-impedance analog and digital power-supply common returns, with wide trace widths, are essential for quiet operation of the MAX178.

Noise

To minimize input noise coupling, input signal leads to AIN and signal return leads from AGND should be kept as short as possible. A shielded cable between source and ADC is suggested in applications where longer leads are required. Also, care should be taken to reduce ground circuit impedances as much as possible since any potential difference in grounds between the signal source and ADC creates an error voltage in series with the input signal.

When interfacing to continuously busy and noisy μP buses, it is possible to get errors at the LSB level. These errors exist because of feedthrough from the bus to the integrated circuit through the package. The problem can be minimized in ceramic packaged chips by grounding the metal lid. Another solution is to isolate the MAX178 from the noisy μP bus using three-state buffers.

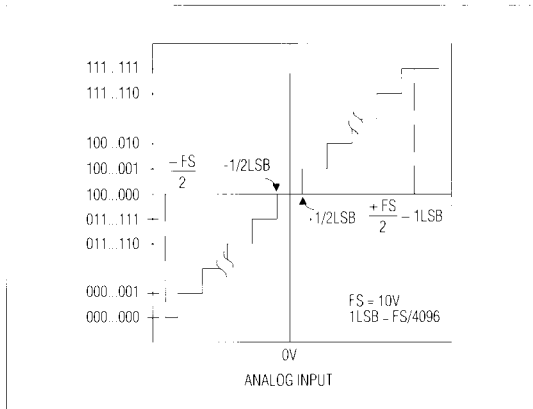


Figure 15. Ideal Input/Output Transfer Characteristic for Bipolar Circuit of Figure 14

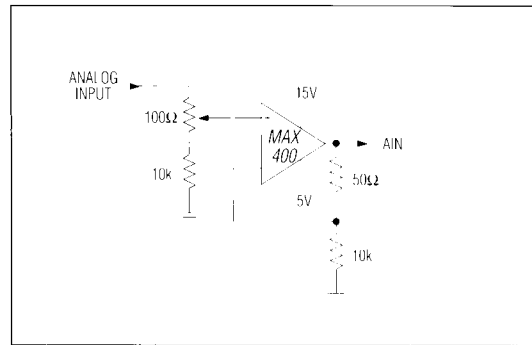


Figure 17. Adjusting Analog Input Gain to Trim Out Initial Reference Voltage Error

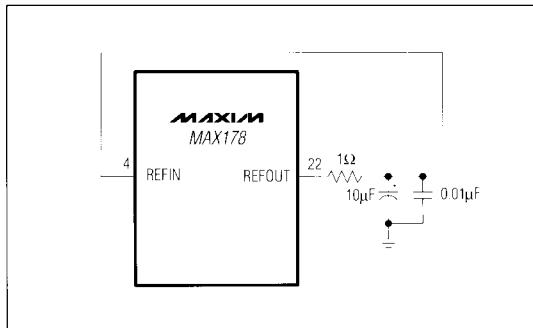


Figure 16. Internal Reference Hookup. Note: Reference Value Is Not Adjustable.

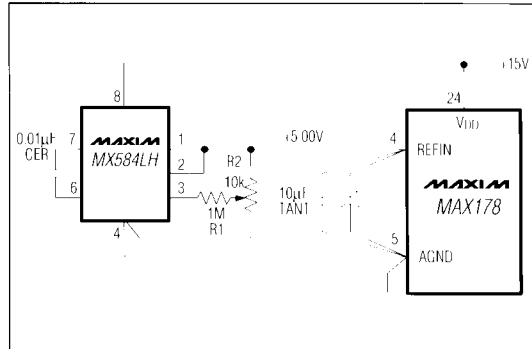
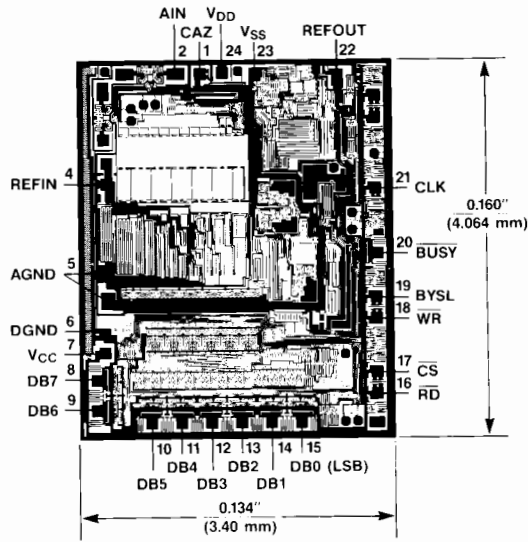


Figure 18. MX584LH as Reference Generator

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Chip Topography

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